

Rolando Saniz

List of Publications by Year in descending order

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papers

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14
times ranked

485
citing authors

#	ARTICLE	IF	CITATIONS
1	First-principles study of defects at grain boundaries in CuGaSe ₃ . Physical Chemistry Chemical Physics, 2017, 19, 14770-14780.	1.9	3
2	Charge Localization and Magnetic Correlations in the Refined Structure of U ₃ O ₇ . Inorganic Chemistry, 2021, 60, 10550-10564.	4.0	6
3	Nature of the Positron State in CdSe Quantum Dots. Physical Review Letters, 2018, 121, 057401.	7.8	7
4	Sulfur-alloyed Cr ₂ O ₃ : a new p-type transparent conducting oxide host. RSC Advances, 2017, 7, 4453-4459.	3.6	9
5	Structural and electronic properties of defects at grain boundaries in CuInSe ₂ . Physical Chemistry Chemical Physics, 2017, 19, 14770-14780.	2.8	16
6	Application of the weighted-density approximation to the accurate description of electron-positron correlation effects in materials. Physical Review B, 2017, 96, .	3.2	7
7	Auger electron emission initiated by the creation of valence-band holes in graphene by positron annihilation. Nature Communications, 2017, 8, 16116.	12.8	25
8	Positron surface state as a spectroscopic probe for characterizing surfaces of topological insulator materials. Physical Review B, 2016, 94, .	3.2	15
9	First-principles analysis of the spectroscopic limited maximum efficiency of photovoltaic absorber layers for CuAu-like chalcogenides and silicon. Physical Chemistry Chemical Physics, 2016, 18, 20542-20549.	2.8	54
10	First-principles study of carbon impurities in CuInSe ₂ and CuGaSe ₂ , present in non-vacuum synthesis methods. Journal of Applied Physics, 2015, 117, 015104.	2.5	5
11	Native point defects in CuIn _{1-x} Ga _x Se ₂ : hybrid density functional calculations predict the origin of p- and n-type conductivity. Physical Chemistry Chemical Physics, 2014, 16, 22299-22308.	2.8	44
12	A simplified approach to the band gap correction of defect formation energies: Al, Ga, and In-doped ZnO. Journal of Physics and Chemistry of Solids, 2013, 74, 45-50.	4.0	38
13	van der Waals bonding and the quasiparticle band structure of SnO from first principles. Physical Review B, 2013, 87, .	3.2	55